# MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A

1.5 A, Step-Up/Down/ Inverting Switching Regulators

The MC34063A Series is a monolithic control circuit containing the primary functions required for DC−to−DC converters. These devices consist of an internal temperature compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in Step−Down and Step−Up and Voltage−Inverting applications with a minimum number of external components. Refer to Application Notes AN920A/D and AN954/D for additional design information.

Features

- Operation from 3.0 V to 40 V Input
- Low Standby Current
- Current Limiting
- Output Switch Current to 1.5 A
- Output Voltage Adjustable
- Frequency Operation to 100 kHz
- Precision 2% Reference
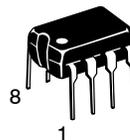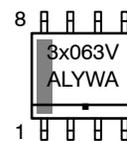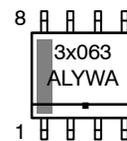- Pb−Free Packages are Available
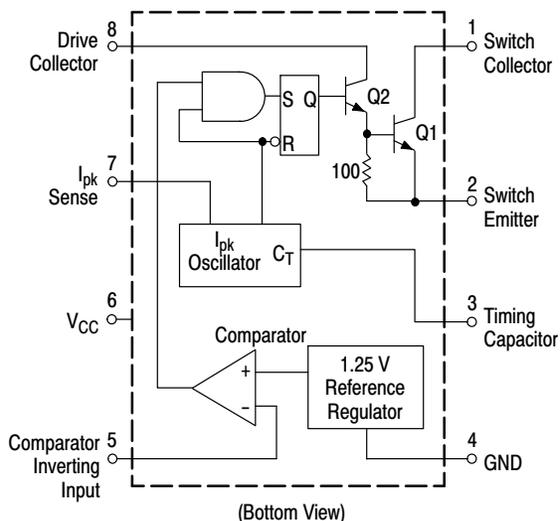
This device contains 79 active transistors.

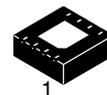**Figure 1. Representative Schematic Diagram**

ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS

SOIC−8
D SUFFIX
CASE 751

3x063
ALYWA

3x063V
ALYWA

PDIP−8
P, P1 SUFFIX
CASE 626

3x063AP1
AWL
YYWWG

33063AVP
AWL
YYWWG

DFN8
CASE 488AF

33063
ALYWA
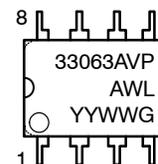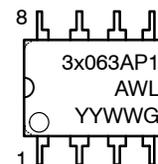
x	= 3 or 4
A	= Assembly Location
L, WL	= Wafer Lot
Y, YY	= Year
W, WW	= Work Week
G or ▪	= Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A

```
  Switch ┌──┐          ┌──┐
Collector │ 1│    ◯     │ 8│  Driver
          └──┘          └──┘  Collector
  Switch  ┌──┐          ┌──┐
 Emitter  │ 2│          │ 7│  I_pk Sense
          └──┘          └──┘
  Timing  ┌──┐          ┌──┐
Capacitor │ 3│          │ 6│  V_CC
          └──┘          └──┘
          ┌──┐          ┌──┐  Comparator
    GND   │ 4│          │ 5│  Inverting
          └──┘          └──┘  Input
          (Top View)
```
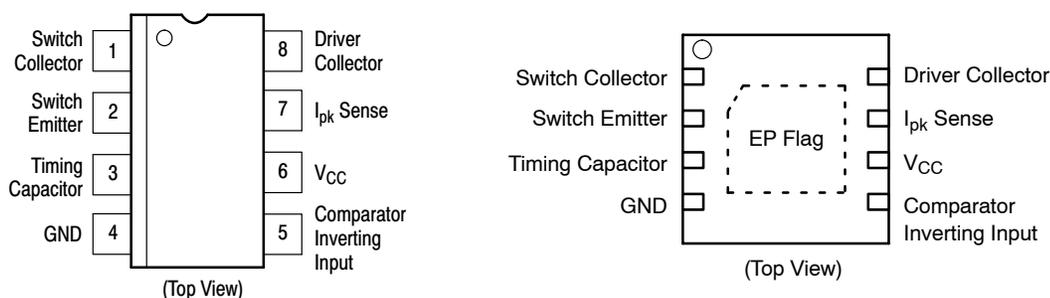
Switch Collector ☐   ◯   ☐ Driver Collector

Switch Emitter ☐   EP Flag   ☐ I_pk Sense

Timing Capacitor ☐   ☐ V_CC

GND ☐   ☐ Comparator Inverting Input

(Top View)

Figure 2. Pin Connections

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}	40	Vdc
Comparator Input Voltage Range	V_{IR}	−0.3 to +40	Vdc
Switch Collector Voltage	$V_{C(switch)}$	40	Vdc
Switch Emitter Voltage ($V_{Pin\ 1}$ = 40 V)	$V_{E(switch)}$	40	Vdc
Switch Collector to Emitter Voltage	$V_{CE(switch)}$	40	Vdc
Driver Collector Voltage	$V_{C(driver)}$	40	Vdc
Driver Collector Current (Note 1)	$I_{C(driver)}$	100	mA
Switch Current	I_{SW}	1.5	A
Power Dissipation and Thermal Characteristics			
Plastic Package, P, P1 Suffix			
T_A = 25°C	P_D	1.25	W
Thermal Resistance	$R_{\theta JA}$	115	°C/W
SOIC Package, D Suffix			
T_A = 25°C	P_D	625	mW
Thermal Resistance	$R_{\theta JA}$	160	°C/W
DFN Package			
T_A = 25°C	P_D	1.25	mW
Thermal Resistance	$R_{\theta JA}$	80	°C/W
Operating Junction Temperature	T_J	+150	°C
Operating Ambient Temperature Range	T_A		°C
MC34063A, SC34063A		0 to +70	
MC33063AV, NCV33063A		−40 to +125	
MC33063A, SC33063A		−40 to +85	
Storage Temperature Range	T_{stg}	−65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. Maximum package power dissipation limits must be observed.
2. This device series contains ESD protection and exceeds the following tests: Human Body Model 4000 V per MIL−STD−883, Method 3015. Machine Model Method 400 V.
3. NCV prefix is for automotive and other applications requiring site and change control.

MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A

ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V, T_A = T_{low} to T_{high} [Note 4], unless otherwise specified.)

Characteristics	Symbol	Min	Typ	Max	Unit
OSCILLATOR					
Frequency ($V_{Pin\,5}$ = 0 V, C_T = 1.0 nF, T_A = 25°C)	f_{osc}	24	33	42	kHz
Charge Current (V_{CC} = 5.0 V to 40 V, T_A = 25°C)	I_{chg}	24	35	42	μA
Discharge Current (V_{CC} = 5.0 V to 40 V, T_A = 25°C)	I_{dischg}	140	220	260	μA
Discharge to Charge Current Ratio (Pin 7 to V_{CC}, T_A = 25°C)	I_{dischg}/I_{chg}	5.2	6.5	7.5	–
Current Limit Sense Voltage (I_{chg} = I_{dischg}, T_A = 25°C)	$V_{ipk(sense)}$	250	300	350	mV
OUTPUT SWITCH (Note 5)					
Saturation Voltage, Darlington Connection (I_{SW} = 1.0 A, Pins 1, 8 connected)	$V_{CE(sat)}$	–	1.0	1.3	V
Saturation Voltage (Note 6) (I_{SW} = 1.0 A, $R_{Pin\,8}$ = 82 Ω to V_{CC}, Forced β ≃ 20)	$V_{CE(sat)}$	–	0.45	0.7	V
DC Current Gain (I_{SW} = 1.0 A, V_{CE} = 5.0 V, T_A = 25°C)	h_{FE}	50	75	–	–
Collector Off–State Current (V_{CE} = 40 V)	$I_{C(off)}$	–	0.01	100	μA
COMPARATOR					
Threshold Voltage T_A = 25°C T_A = T_{low} to T_{high}	V_{th}	1.225 1.21	1.25 –	1.275 1.29	V
Threshold Voltage Line Regulation (V_{CC} = 3.0 V to 40 V) MC33063, MC34063 MC33063V, NCV33063	Reg_{line}	 – –	 1.4 1.4	 5.0 6.0	mV
Input Bias Current (V_{in} = 0 V)	I_{IB}	–	−20	−400	nA
TOTAL DEVICE					
Supply Current (V_{CC} = 5.0 V to 40 V, C_T = 1.0 nF, Pin 7 = V_{CC}, $V_{Pin\,5}$ > V_{th}, Pin 2 = GND, remaining pins open)	I_{CC}	–	–	4.0	mA

4. T_{low} = 0°C for MC34063, SC34063; − 40°C for MC33063, SC33063, MC33063V, NCV33063
   T_{high} = +70°C for MC34063, SC34063; + 85°C for MC33063, SC33063; +125°C for MC33063V, NCV33063
5. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.
6. If the output switch is driven into hard saturation (non–Darlington configuration) at low switch currents (≤ 300 mA) and high driver currents (≥ 30 mA), it may take up to 2.0 μs for it to come out of saturation. This condition will shorten the off time at frequencies ≥ 30 kHz, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non–Darlington configuration is used, the following output drive condition is recommended:

Forced β of output switch : $\dfrac{I_C \text{ output}}{I_C \text{ driver} − 7.0 \text{ mA}^*} \geq 10$

* The 100 Ω resistor in the emitter of the driver device requires about 7.0 mA before the output switch conducts.
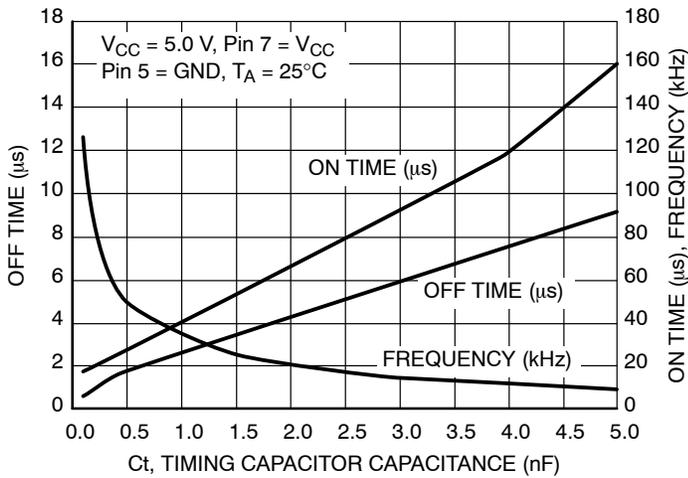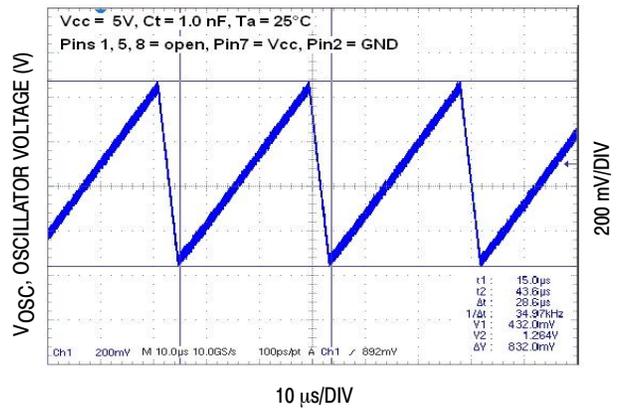
Figure 3. Oscillator Frequency
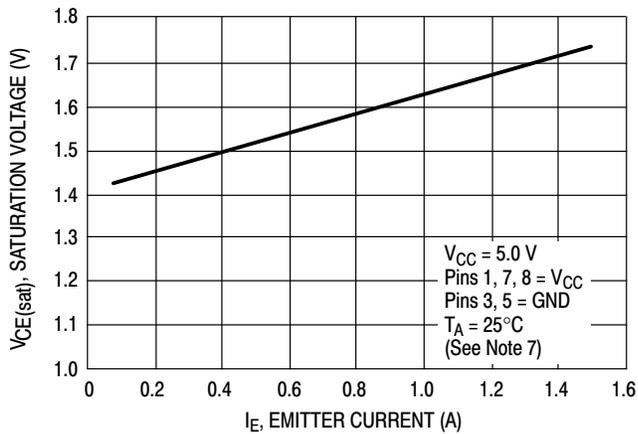
Figure 4. Timing Capacitor Waveform

Figure 5. Emitter Follower Configuration Output Saturation Voltage versus Emitter Current
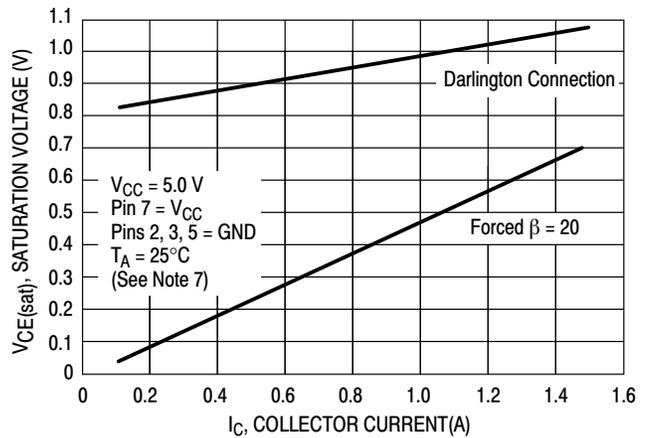
Figure 6. Common Emitter Configuration Output Switch Saturation Voltage versus Collector Current
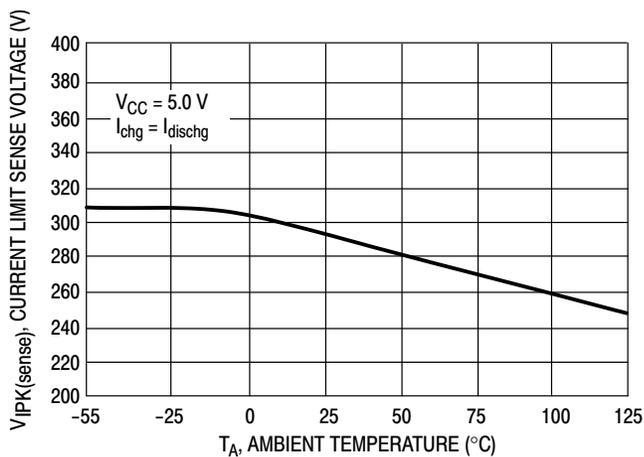
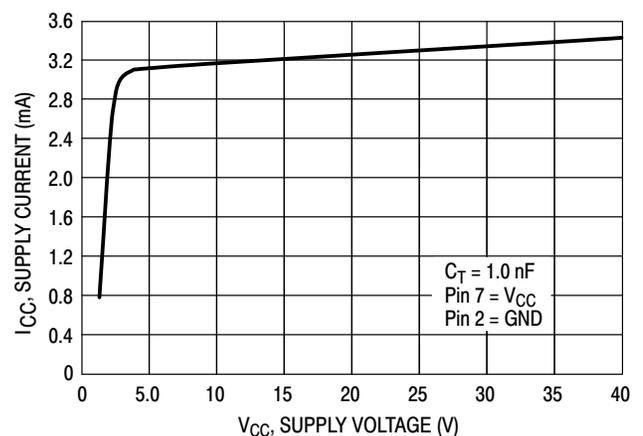**Figure 7. Current Limit Sense Voltage versus Temperature**

Figure 8. Standby Supply Current versus Supply Voltage

7. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.

Figure 9. Step−Up Converter

Test	Conditions	Results
Line Regulation	V_{in} = 8.0 V to 16 V, I_O = 175 mA	30 mV = ±0.05%
Load Regulation	V_{in} = 12 V, I_O = 75 mA to 175 mA	10 mV = ±0.017%
Output Ripple	V_{in} = 12 V, I_O = 175 mA	400 mVpp
Efficiency	V_{in} = 12 V, I_O = 175 mA	87.7%
Output Ripple With Optional Filter	V_{in} = 12 V, I_O = 175 mA	40 mVpp
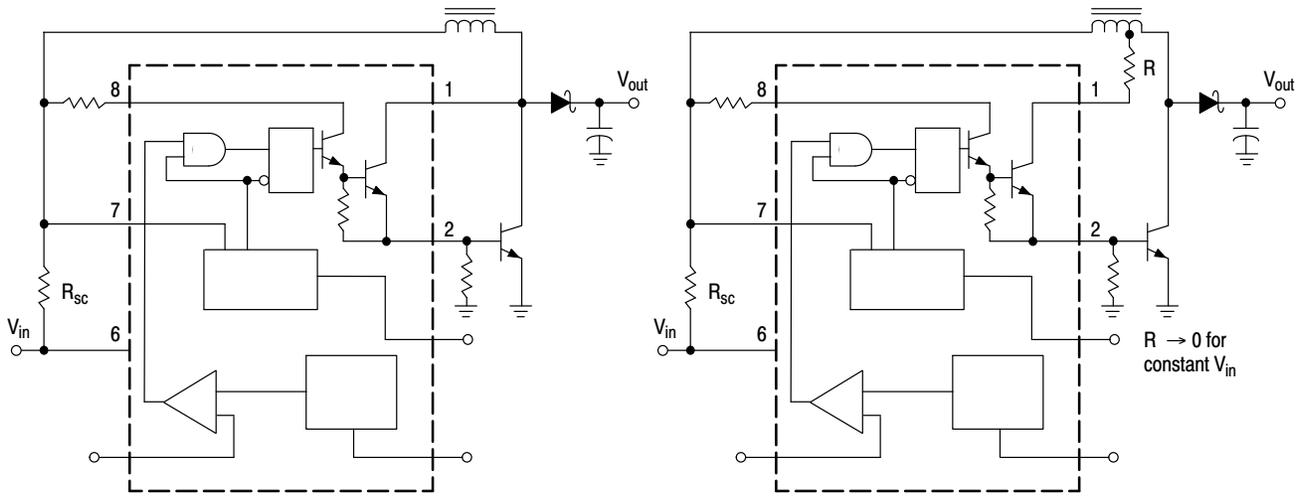
**Figure 10. External Current Boost Connections for I_C Peak Greater than 1.5 A**

9a. External NPN Switch

9b. External NPN Saturated Switch

(See Note 8)

8. If the output switch is driven into hard saturation (non–Darlington configuration) at low switch currents (≤ 300 mA) and high driver currents (≥ 30 mA), it may take up to 2.0 μs to come out of saturation. This condition will shorten the off time at frequencies ≥ 30 kHz, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non–Darlington configuration is used, the following output drive condition is recommended.

MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A
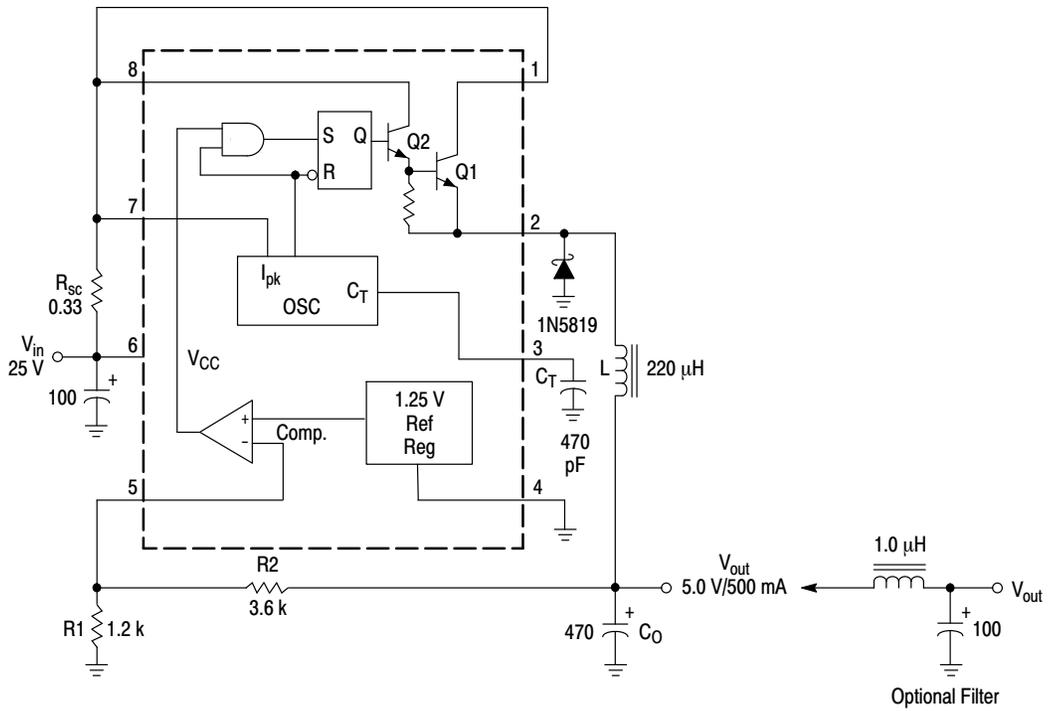
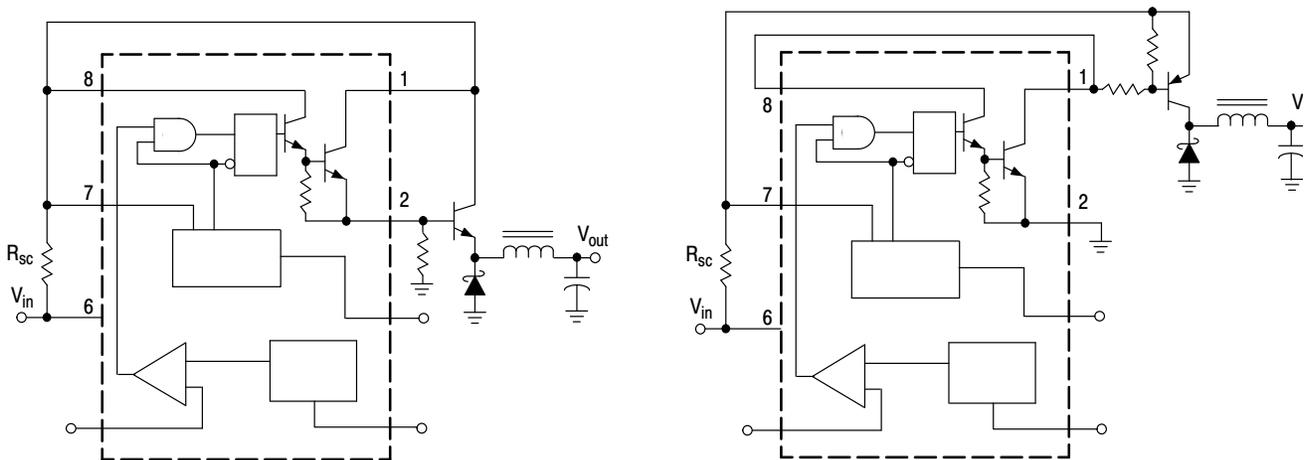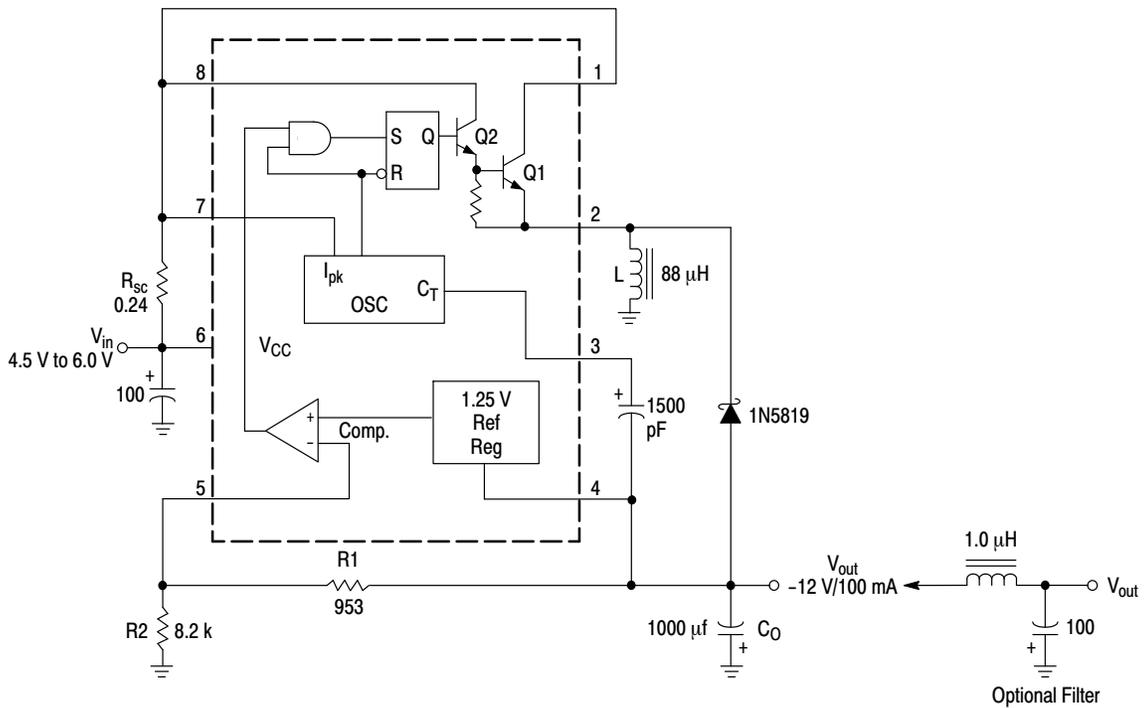| Test	Conditions	Results
Line Regulation	V_{in} = 15 V to 25 V, I_O = 500 mA	12 mV = ±0.12%
Load Regulation	V_{in} = 25 V, I_O = 50 mA to 500 mA	3.0 mV = ±0.03%
Output Ripple	V_{in} = 25 V, I_O = 500 mA	120 mVpp
Short Circuit Current	V_{in} = 25 V, R_L = 0.1 Ω	1.1 A
Efficiency	V_{in} = 25 V, I_O = 500 mA	83.7%
Output Ripple With Optional Filter	V_{in} = 25 V, I_O = 500 mA	40 mVpp

Figure 11. Step−Down Converter

Figure 12. External Current Boost Connections for I_C Peak Greater than 1.5 A

11a. External NPN Switch　　　　　　　　　　**11b. External PNP Saturated Switch**

Test	Conditions	Results
Line Regulation	V_{in} = 4.5 V to 6.0 V, I_O = 100 mA	3.0 mV = ±0.012%
Load Regulation	V_{in} = 5.0 V, I_O = 10 mA to 100 mA	0.022 V = ±0.09%
Output Ripple	V_{in} = 5.0 V, I_O = 100 mA	500 mVpp
Short Circuit Current	V_{in} = 5.0 V, R_L = 0.1 Ω	910 mA
Efficiency	V_{in} = 5.0 V, I_O = 100 mA	62.2%
Output Ripple With Optional Filter	V_{in} = 5.0 V, I_O = 100 mA	70 mVpp

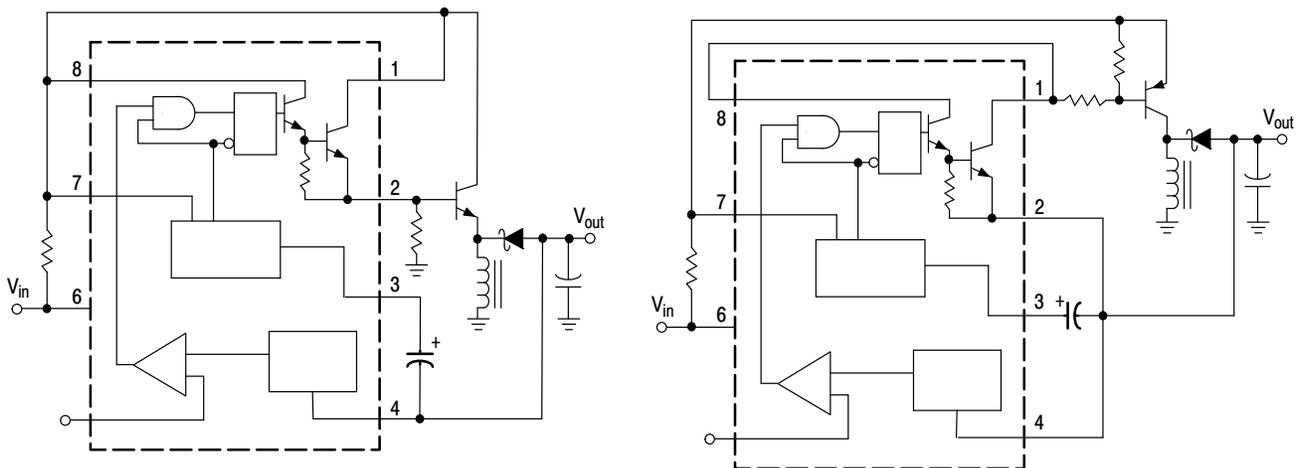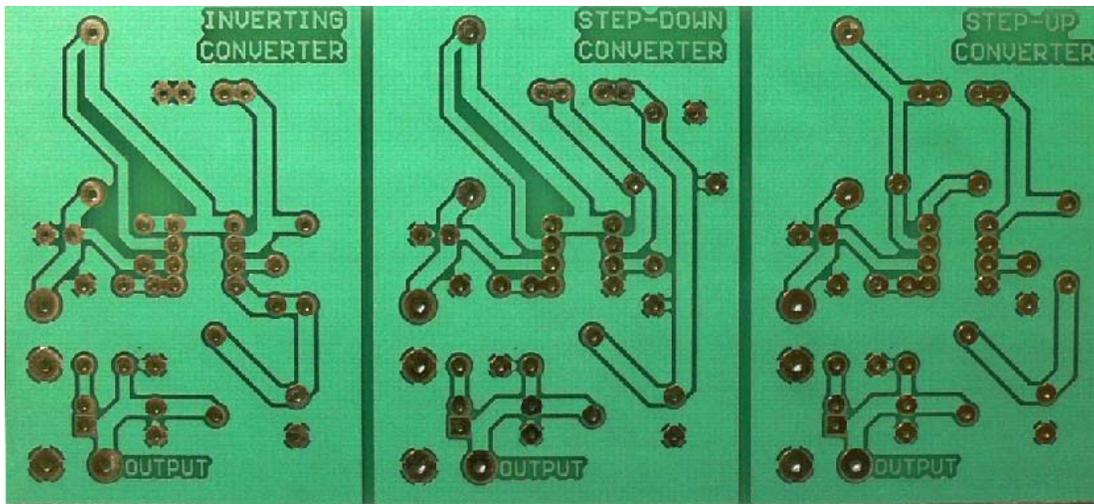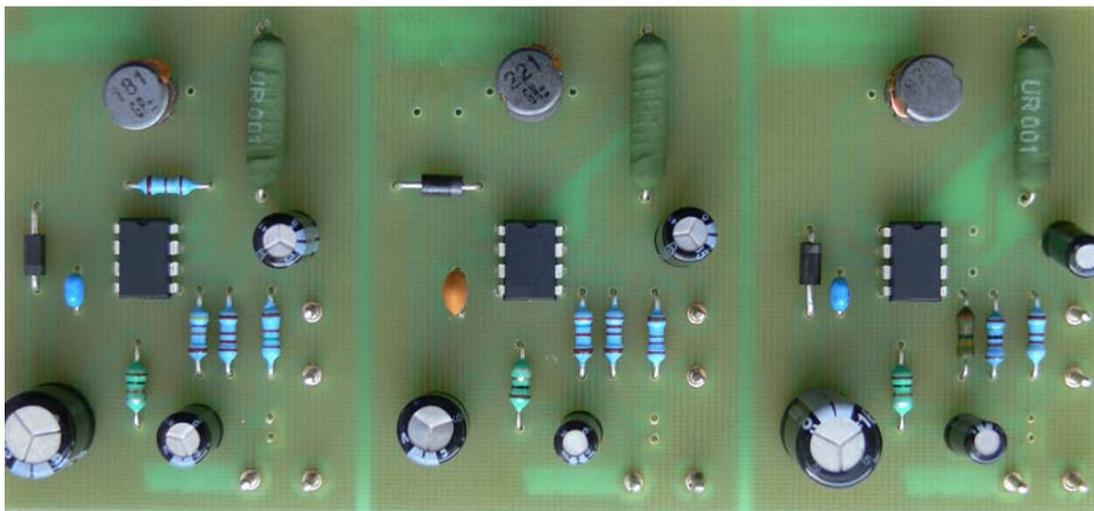**Figure 13. Voltage Inverting Converter**

Figure 14. External Current Boost Connections for I_C Peak Greater than 1.5 A

13a. External NPN Switch   **13b. External PNP Saturated Switch**

(Bottom Side)

(Top View, Component Side)

Figure 15. Printed Circuit Board and Component Layout
(Circuits of Figures 9, 11, 13)

INDUCTOR DATA

Converter	Inductance (μH)	Turns/Wire
Step–Up	170	38 Turns of #22 AWG
Step–Down	220	48 Turns of #22 AWG
Voltage–Inverting	88	28 Turns of #22 AWG

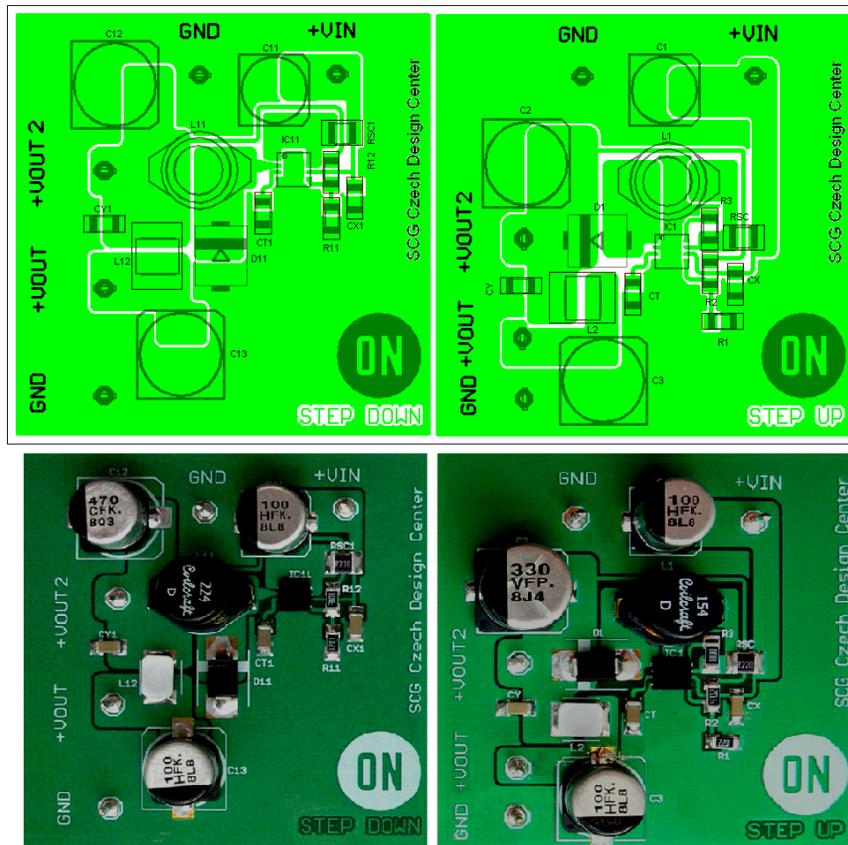All inductors are wound on Magnetics Inc. 55117 toroidal core.

Figure 16. Printed Circuit Board for DFN Device

Calculation	Step–Up	Step–Down	Voltage–Inverting
t_{on}/t_{off}	$\dfrac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\dfrac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\dfrac{|V_{out}| + V_F}{V_{in} - V_{sat}}$
$(t_{on} + t_{off})$	$\dfrac{1}{f}$	$\dfrac{1}{f}$	$\dfrac{1}{f}$
t_{off}	$\dfrac{t_{on} + t_{off}}{\dfrac{t_{on}}{t_{off}} + 1}$	$\dfrac{t_{on} + t_{off}}{\dfrac{t_{on}}{t_{off}} + 1}$	$\dfrac{t_{on} + t_{off}}{\dfrac{t_{on}}{t_{off}} + 1}$
t_{on}	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$
C_T	$4.0 \times 10^{-5}\, t_{on}$	$4.0 \times 10^{-5}\, t_{on}$	$4.0 \times 10^{-5}\, t_{on}$
$I_{pk(switch)}$	$2I_{out(max)}\left(\dfrac{t_{on}}{t_{off}} + 1\right)$	$2I_{out(max)}$	$2I_{out(max)}\left(\dfrac{t_{on}}{t_{off}} + 1\right)$
R_{sc}	$0.3/I_{pk(switch)}$	$0.3/I_{pk(switch)}$	$0.3/I_{pk(switch)}$
$L_{(min)}$	$\left(\dfrac{(V_{in(min)} - V_{sat})}{I_{pk(switch)}}\right) t_{on(max)}$	$\left(\dfrac{(V_{in(min)} - V_{sat} - V_{out})}{I_{pk(switch)}}\right) t_{on(max)}$	$\left(\dfrac{(V_{in(min)} - V_{sat})}{I_{pk(switch)}}\right) t_{on(max)}$
C_O	$9\dfrac{I_{out}t_{on}}{V_{ripple(pp)}}$	$\dfrac{I_{pk(switch)}(t_{on} + t_{off})}{8V_{ripple(pp)}}$	$9\dfrac{I_{out}t_{on}}{V_{ripple(pp)}}$

V_{sat} = Saturation voltage of the output switch.
V_F = Forward voltage drop of the output rectifier.

The following power supply characteristics must be chosen:

V_{in} – Nominal input voltage.
V_{out} – Desired output voltage, $|V_{out}| = 1.25\left(1 + \dfrac{R2}{R1}\right)$
I_{out} – Desired output current.
f_{min} – Minimum desired output switching frequency at the selected values of V_{in} and I_O.
$V_{ripple(pp)}$ – Desired peak–to–peak output ripple voltage. In practice, the calculated capacitor value will need to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

NOTE: For further information refer to Application Note AN920A/D and AN954/D.

Figure 17. Design Formula Table

# MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A

ORDERING INFORMATION

Device	Package	Shipping†
MC33063AD	SOIC−8	98 Units / Rail
MC33063ADG	SOIC−8 (Pb−Free)	98 Units / Rail
MC33063ADR2	SOIC−8	2500 Units / Tape & Reel
MC33063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
SC33063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
MC33063AP1	PDIP−8	50 Units / Rail
MC33063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
MC33063AVD	SOIC−8	98 Units / Rail
MC33063AVDG	SOIC−8 (Pb−Free)	98 Units / Rail
MC33063AVDR2	SOIC−8	2500 Units / Tape & Reel
MC33063AVDR2G	SOIC−8 (Pb−Free)	
NCV33063AVDR2*	SOIC−8	
NCV33063AVDR2G*	SOIC−8 (Pb−Free)	
MC33063AVP	PDIP−8	50 Units / Rail
MC33063AVPG	PDIP−8 (Pb−Free)	50 Units / Rail
MC34063AD	SOIC−8	98 Units / Rail
MC34063ADG	SOIC−8 (Pb−Free)	98 Units / Rail
MC34063ADR2	SOIC−8	2500 Units / Tape & Reel
MC34063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
SC34063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
MC34063AP1	PDIP−8	50 Units / Rail
MC34063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
SC34063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
MC33063MNTXG	DFN8 (Pb−Free)	4000 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*NCV33063A: $T_{low} = -40°C$, $T_{high} = +125°C$. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

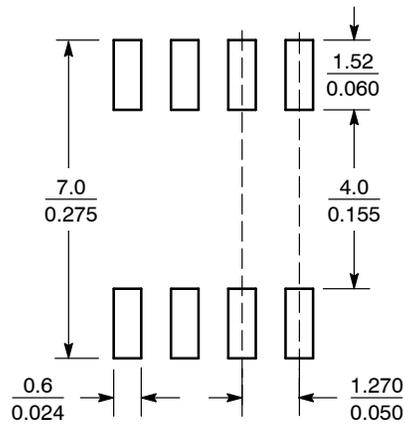## PACKAGE DIMENSIONS

SOIC−8 NB
CASE 751−07
ISSUE AJ
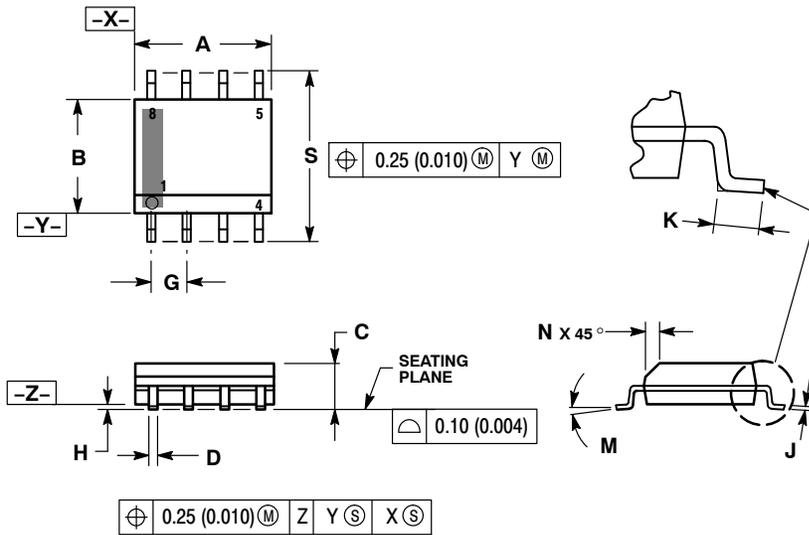
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*

1.52 / 0.060

7.0 / 0.275

4.0 / 0.155

0.6 / 0.024

1.270 / 0.050

SCALE 6:1 $\left(\dfrac{mm}{inches}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS
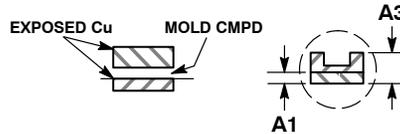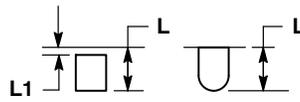
PDIP−8
P, P1 SUFFIX
CASE 626−05
ISSUE M

TOP VIEW

NOTE 5

END VIEW
NOTE 3

SIDE VIEW

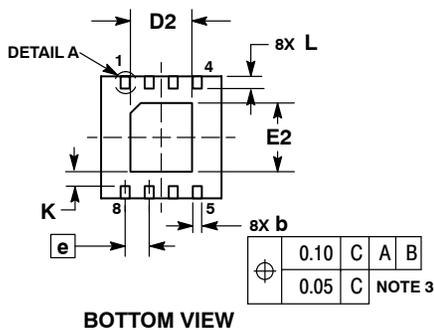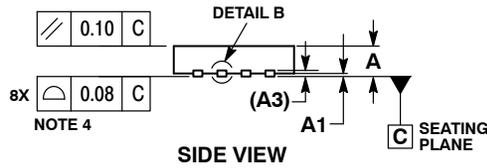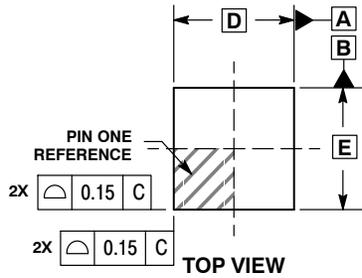$\oplus$ | 0.010 Ⓜ | C | A

END VIEW
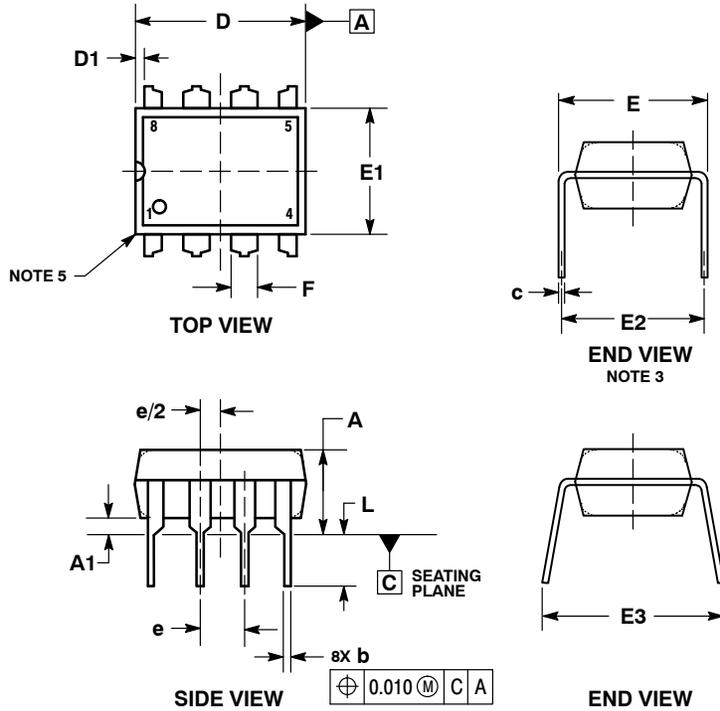
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION E IS MEASURED WITH THE LEADS RE-STRAINED PARALLEL AT WIDTH E2.
4. DIMENSION E1 DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	----	----	0.210	----	----	5.33
A1	0.015	----	----	0.38	----	----
b	0.014	0.018	0.022	0.35	0.46	0.56
C	0.008	0.010	0.014	0.20	0.25	0.36
D	0.355	0.365	0.400	9.02	9.27	10.02
D1	0.005	----	----	0.13	----	----
E	0.300	0.310	0.325	7.62	7.87	8.26
E1	0.240	0.250	0.280	6.10	6.35	7.11
E2	0.300 BSC			7.62 BSC		
E3	----	----	0.430	----	----	10.92
e	0.100 BSC			2.54 BSC		
L	0.115	0.130	0.150	2.92	3.30	3.81

PACKAGE DIMENSIONS

DFN8, 4x4
CASE 488AF–01
ISSUE C

TOP VIEW

PIN ONE REFERENCE

2X | ⌓ | 0.15 | C

2X | ⌓ | 0.15 | C

D — A
B
E

DETAIL A
OPTIONAL CONSTRUCTIONS

L1

SIDE VIEW

| ⫽ | 0.10 | C

DETAIL B

8X | ⌓ | 0.08 | C
NOTE 4

(A3)
A1
A

C SEATING PLANE

EXPOSED Cu   MOLD CMPD

DETAIL B
ALTERNATE CONSTRUCTIONS

A3
A1

NOTES:
1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. DETAILS A AND B SHOW OPTIONAL CONSTRUCTIONS FOR TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20 REF	
b	0.25	0.35
D	4.00 BSC	
D2	1.91	2.21
E	4.00 BSC	
E2	2.09	2.39
e	0.80 BSC	
K	0.20	---
L	0.30	0.50
L1	---	0.15

BOTTOM VIEW

DETAIL A
D2
8X L
E2
K
8
5
e
8X b

| ⊕ | 0.10 | C | A | B |
| ⊕ | 0.05 | C | NOTE 3 | |

SOLDERING FOOTPRINT*

2.21
8X 0.63
4.30
2.39
PACKAGE OUTLINE
0.80 PITCH
8X 0.35
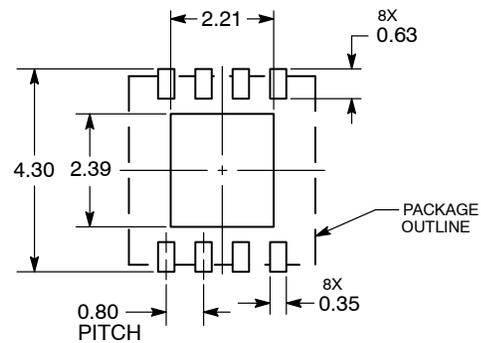
DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MC34063A/D

ООО "ЛайфЭлектроникс"   **"LifeElectronics" LLC**

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.

- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.

- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.